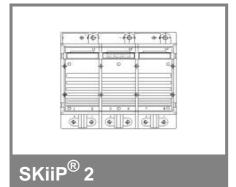
## SKiiP 232GD120-3DU



### 6-pack - integrated intelligent Power System

**Power section** 

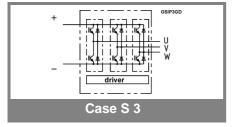
SKiiP 232GD120-3DU

#### **Features**

- SKiiP technology inside
- CAL diode technology
- Integrated current sensor
- Integrated temperature sensor
- Integrated heat sink
- IEC 60721-3-3 (humidity) class 3K3/IE32 (SKiiP® 2 System)
- IEC 60068-1 (climate) 40/125/56
  UL recognized file no. E63532
- 1) with assembly of suitable MKP capacitor per terminal (SEMIKRON type is recommended)

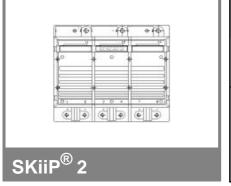
Absolute	Maximum Ratings	s = 25 °C unless otherwise specified				
Symbol	Conditions	Values	Units			
IGBT						
$V_{CES}$		1200	V			
V <sub>CES</sub> V <sub>CC</sub> 1)	Operating DC link voltage	900	V			
$V_{GES}$		± 20	V			
I <sub>C</sub>	T <sub>s</sub> = 25 (70) °C	200 (150)	Α			
Inverse diode						
I <sub>F</sub> = - I <sub>C</sub>	T <sub>s</sub> = 25 (70) °C	200 (150)	Α			
I <sub>FSM</sub>	$T_i = 150 ^{\circ}\text{C},  t_p = 10 \text{ms};  \text{sin}.$	1440	Α			
I²t (Diode)	Diode, T <sub>j</sub> = 150 °C, 10 ms	10	kA²s			
$T_j$ , $(T_{stg})$		- 40 (- 25) + 150 (125)	°C			
V <sub>isol</sub>	AC, 1 min. (mainterminals to heat sink)	3000	V			

	•							
Characteristics T <sub>s</sub>					$T_s$ = 25 $^\circ$	C unless	otherwise	specified
Symbol	Condition	ons			min.	typ.	max.	Units
IGBT	1				ı			
$V_{CEsat}$	I <sub>C</sub> = 175 A	, T <sub>i</sub> = 25 (1	25) °C			2,6 (3,1)	3,1	V
V <sub>CEO</sub>	$T_i = 25 (12)$					1,2 (1,3)	1,5 (1,6)	V
$r_{CE}$	$T_j = 25 (12)$	25) °C				7,5 (10)	9 (11,5)	mΩ
I <sub>CES</sub>	$V_{GE} = 0 V$	, V <sub>CE</sub> = V <sub>CE</sub>	S,			(10)	0,4	mA
	$T_j = 25 (12)$	25) °C						
E <sub>on</sub> + E <sub>off</sub>	I <sub>C</sub> = 175 A	, V <sub>CC</sub> = 600	) V				53	mJ
		$C, V_{CC} = 90$					93	mJ
R <sub>CC' + EE'</sub>	terminal cl	hip, T <sub>i</sub> = 12	5 °C			0,5		mΩ
L <sub>CE</sub>	top, bottor	m ´				15		nH
C <sub>CHC</sub>	per phase	, AC-side				1,4		nF
Inverse o	diode							
$V_F = V_{EC}$	I <sub>F</sub> = 150 A	., T <sub>j</sub> = 25 (1	25) °C			2,1 (1,9)	2,6	V
$V_{TO}$	$T_j = 25 (12)$					1,3 (1)	,	V
r <sub>T</sub>	$T_j = 25 (12)$					5 (6)	6,8 (7,8)	mΩ
E <sub>rr</sub>		$V_{CC} = 600$					7	mJ
	,	$C, V_{CC} = 90$	00 V				9	mJ
Mechani	cal data							
M <sub>dc</sub>		als, SI Unit			6		8	Nm
M <sub>ac</sub>	AC terminals, SI Units				13	0.7	15	Nm
W	SKiiP <sup>®</sup> 2 System w/o heat sink					2,7		kg
W	heat sink					6,6		kg
			P16 hea	it sink; 29	95 m³/h)	; " <sub>r</sub> " refer	ence to	
temperat	•	sor			ſ		0.400	1.000
R <sub>th(j-s)I</sub>	per IGBT						0,129	K/W K/W
R <sub>th(j-s)D</sub>	per diode	_					0,375	
R <sub>th(s-a)</sub>	per modul						0,036	K/W
$Z_{th}$	R <sub>i</sub> (mk/vv)	(max. valu	es) 3	4	l 4	tau 2	<sub>i</sub> (s) 3	4
7	14	2 99	ა 15	0	1 1	∠ 0,13	0,001	1
Z <sub>th(j-r)I</sub>	41	289	45	0	'1	0,13	0,001	1
Z <sub>th(j-r)D</sub>	11,1	18,3	3,5	3,1	204	60	6	0,02
$Z_{th(r-a)}$	' ', '	10,5	3,3	٥, ١	204	00	U	0,02



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## **SKiiP 232GD120-3DU**



Absolute Maximum Ratings		<sub>a</sub> = 25 °C unless otherwise specified		
Symbol	Conditions	Values	Units	
$V_{S1}$	stabilized 15 V power supply	18	V	
$V_{S2}$	unstabilized 24 V power supply	30	V	
$V_{iH}$	input signal voltage (high)	15 + 0,3	V	
dv/dt	secondary to primary side	75	kV/μs	
$V_{isollO}$	input / output (AC, r.m.s., 2s)	3000	Vac	
V <sub>isol12</sub>	output 1 / output 2 (AC, r.m.s., 2s)	1500	Vac	
f <sub>sw</sub>	switching frequency	20	kHz	
f <sub>out</sub>	output frequency for I=I <sub>C</sub> ;sin.	1	kHz	
$T_{op} (T_{stg})$	operating / storage temperature	- 40 <b>+</b> 85	°C	

# 6-pack - integrated intelligent Power System

6-pack integrated gate driver

**SKiiP 232GD120-3DU** 

#### **Gate driver features**

- · CMOS compatible inputs
- Wide range power supply
- Integrated circuitry to sense phase current, heat sink temperature and DC-bus voltage (option)
- · Short circuit protection
- · Over current protection
- Over voltage protection (option)
- Power supply protected against under voltage
- · Interlock of top/bottom switch
- Isolation by transformer
- IEC 60068-1 (climate) 25/85/56

Characte	eristics		$(T_a = 25)$		
Symbol	Conditions	min.	typ.	max.	Units
V <sub>S1</sub>	supply voltage stabilized	14,4	15	15,6	V
$V_{S2}$	supply voltage non stabilized	20	24	30	V
I <sub>S1</sub>	V <sub>S1</sub> = 15 V	410+390	410+390*f/f <sub>max</sub> +3,6*(I <sub>AC</sub> /A)		
I <sub>S2</sub>	V <sub>S2</sub> = 24 V	300+280	300+280*f/f <sub>max</sub> +2,6*(I <sub>AC</sub> /A)		
V <sub>iT+</sub>	input threshold voltage (High)			12,3	V
$V_{iT-}$	input threshold voltage (Low)	4,6			V
R <sub>IN</sub>	input resistance		10		kΩ
t <sub>d(on)IO</sub>	input-output turn-on propagation time			1,5	μs
t <sub>d(off)IO</sub>	input-output turn-off propagation time			1,4	μs
tpERRRESET	error memory reset time	9			μs
t <sub>TD</sub>	top / bottom switch : interlock time		2,3		μs
I <sub>analogOUT</sub>	8 V corresponds to max. current of 15 V supply voltage		200		Α
1	(available when supplied with 24 V)			50	mA
Vs1outmax	output current at pin 13/20/22/24/26			5	mA
I <sub>A0max</sub> V <sub>0I</sub>	logic low output voltage			0,6	V
	, ,			30	V
V <sub>0H</sub>	logic high output voltage			30	
ITRIPSC	over current trip level (I <sub>analog OUT</sub> = 10 V)		250		Α
ITRIPLG	ground fault protection		58		Α
$T_tp$	over temperature protection	110		120	°C
$U_{DCTRIP}$	trip level of U <sub>DC</sub> -protection	900			V
	( U <sub>analog OUT</sub> = 9 V); (option)				

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